

/ Descriptions

TO-126F NPN Silicon NPN transistor in a TO-126F Plastic Package.

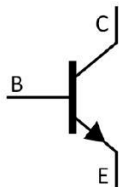
/ Features

$V_{CE(sat)}$, 2SA885 3W
Low $V_{CE(sat)}$, 3W output in complementary pair with 2SA885.

/ Applications

Medium power amplifier.

/ Equivalent Circuit



/ Pinning



PIN1 Emitter PIN 2 Collector PIN 3 Base

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	Q	R	S
h_{FE} Range	85~170	120~240	170~340

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	45	V
Collector to Emitter Voltage	V_{CEO}	35	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	1.0	A
Collector Current – Continuous(Pulse)	I_{CP}	1.5	A
Collector Power Dissipation	$*P_C$	1.2	W
Collector Power Dissipation	$**P_C$	5	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

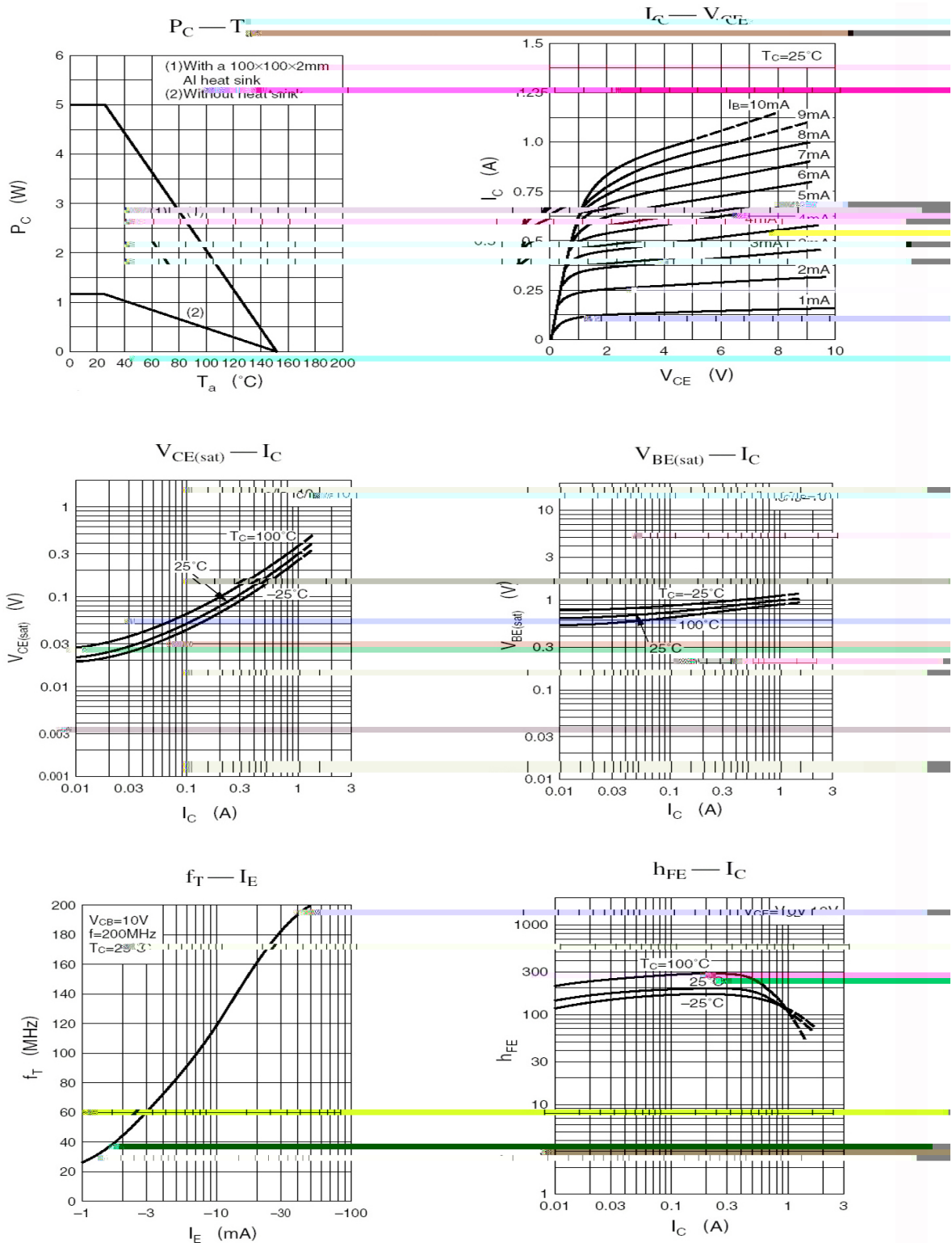
*Without heat sink

**With a 100×100×2mm AL heat sink

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=1.0mA$ $I_E=0$	45			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=2.0mA$ $I_B=0$	35			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=20V$ $I_E=0$			0.1	A
Collector Cut-Off Current	I_{CEO}	$V_{CE}=20V$ $I_B=0$			100	A
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			10	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=10V$ $I_C=500mA$	85	160	340	
	$h_{FE(2)}$	$V_{CE}=5.0V$ $I_C=1.0A$	50			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500mA$ $I_B=50mA$			0.5	V
Transition Frequency	f_T	$V_{CE}=10V$ $I_C=50mA$		200		MHz
Reverse Transfer Capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$ $I_E=0$			20	pF

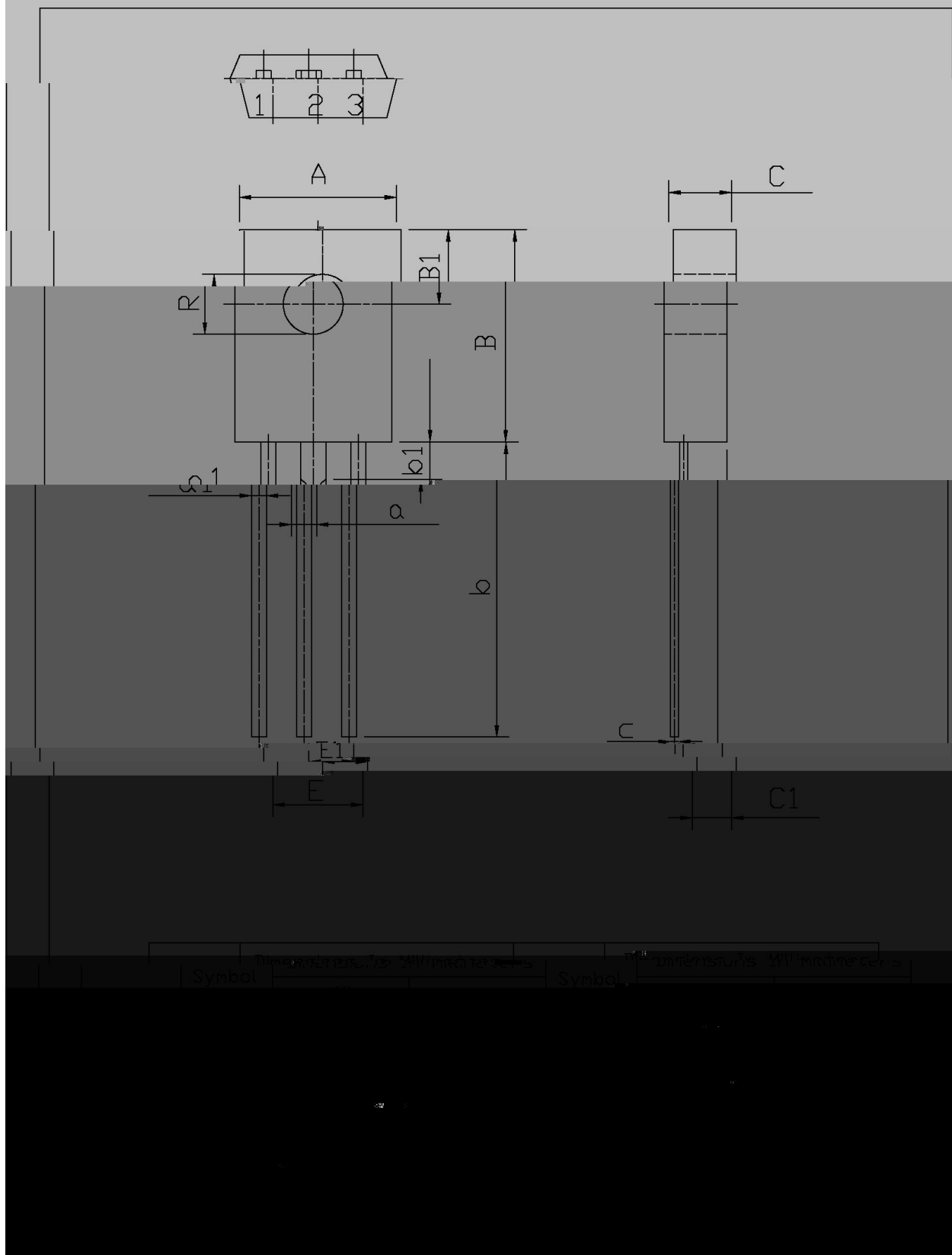
/ Electrical Characteristic Curve



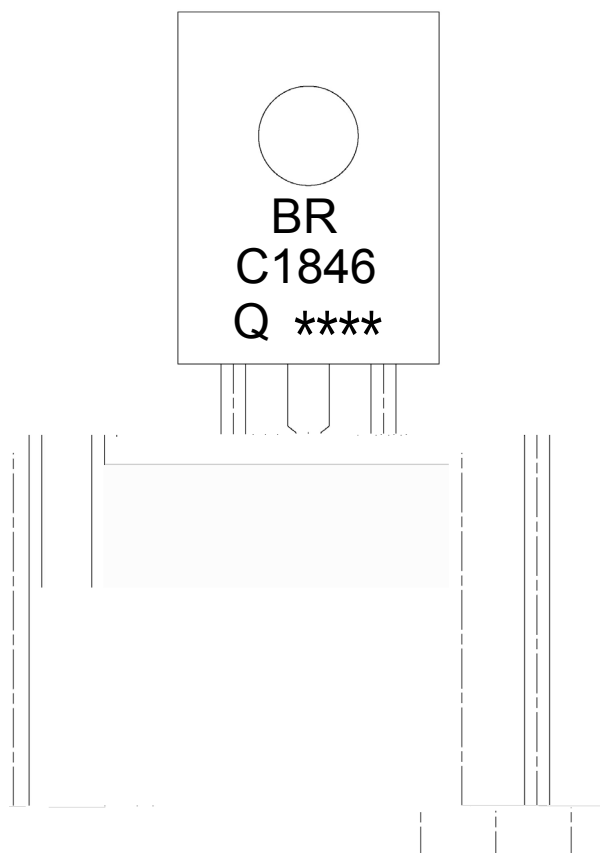
/ Package Dimensions

TU-126F

单位: mm



/ Marking Instructions



BR

C1846

Q: h_{FE}

Note:

BR: Company Code

C1846: Product Type.

Q: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;

2

255±5

5±0.5sec;
- 3

2 10

/sec.

1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

nce to Soldering Heat Test Conditions

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ Packaging SPEC.

/ BLANK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-126/F	500	6	3,000	5	15,000	135×190	237×172×102	560×245×195

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
							555×164×50	575×290×180